TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7SBD385AFU

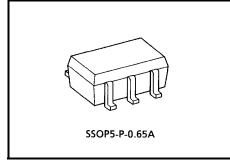
#### Single Bus Switch with Level Shifting

The TC7SBD385AFU provides single bit of high-speed TTL-compatible switching. The low on resistance of the switch allows connections to be made with minimal propagation delay.

The device is organized as just 1-bit low-impedance switch with output-enable (OE) input. When OE is high, the switch is on and data can flow from port A to port B, or vice versa. When OE is low, the switch is open and a high-impedance state exists between the two ports.

The device is enable to realize the shift of signal level from 5 V to 3 3 V  $\,$ 

All inputs are equipped with protection circuits against static discharge.



Weight: 0.006 g (typ.)

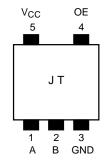
#### **Features**

- Operating voltage: VCC = 4.5~5.5 V
- High speed operation: tpd = 0.32 ns (max)
- Low on resistance:  $RON = 5 \Omega$  (typ.)
- ESD performance: Machine model > ±200 V

Human body model  $> \pm 2000 \text{ V}$ 

- TTL level input (control input)
- Low Power Dissipation: Icc = 10 μA (max.)
- Package: USV

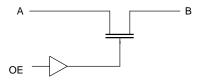
#### Pin Assignment (top view)



## **Truth Table**

Input	Function
OE	Tunction
L	Disconnect
Н	A port = B port

## **System Diagram**



## **Absolute Maximum Ratings (Note)**

Characteristics	Symbol	Rating	Unit	
Power supply range	$V_{CC}$	-0.5~7.0	V	
DC input voltage	V <sub>IN</sub>	-0.5~7.0	V	
DC switch voltage	Vs	-0.5~7.0	V	
Input diode current	I <sub>IK</sub>	-50	mA	
Continuous channel current	IS	128	mA	
Power dissipation	$P_{D}$	200	mW	
DC V <sub>CC</sub> /GND current	I <sub>CC</sub> /I <sub>GND</sub>	±100	mA	
Storage temperature	T <sub>stg</sub>	-65~150	°C	

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction

# **Recommended Operating Conditions (Note)**

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	4.5~5.5	V	
Input voltage	V <sub>IN</sub>	0~5.5	V	
Switch voltage	Vs	0~5.5	V	
Operating temperature	T <sub>opr</sub>	-40~85	°C	
Input rise and fall time	dt/dv	0~10	ns/V	

Note: The recommended operating conditions are required to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

#### **Electrical Characteristics**

#### DC Characteristics ( $Ta = -40 \sim 85$ °C)

Charac	teristics	Symbol	Test Condition V <sub>CC</sub> (V)		Min	Typ. (Note 1)	Max	Unit	
Input voltage	"H" level	V <sub>IH</sub>	-	_	4.5~5.5	2.0	_	_	V
Input voltage	"L" level	VIL	-	_	4.5~5.5	_	_	0.8	V
High layed auto			1011 44		4.75	2.3	2.8	3.2	
High-level outp	•	V <sub>OH</sub>	IOH=-1μA		5.0	2.5	3.0	3.4	V
	(Note 2)		VIS = VCC		5.25	2.7	3.2	3.6	
Input leakage of	current	I <sub>IN</sub>	V <sub>IN</sub> = 0~5.5 V		4.5~5.5	_	_	±1.0	μА
Power off leaka	age current	I <sub>OFF</sub>	A, B, OE= 0~5.5 V		0	_	_	±1.0	μА
Off-STATE leaf (switch off)	kage current	I <sub>SZ</sub>	A, B = 0~5.5 V, OE = GND		4.5~5.5	_	_	±1.0	μΑ
				I <sub>IS</sub> = 64 mA	4.5	_	5	9	
				IIS = 64 IIIA	4.75	_	5	8	
ON resistance		D	$V_{IS} = 0 V$	L- 20 m A	4.5	_	5	9	0
	(Note 3)	R <sub>ON</sub>		$I_{IS} = 30 \text{ mA}$	4.75	_	5	8	Ω
			V 22V L 45 m	- ^	4.5	_	35	65	
			$V_{IS} = 2.3 \text{ V}, I_{IS} = 15 \text{ n}$	$A \cap B = S \cap A$		_	35	50	
Quiescent supp	oly current	ICC	VIN = VCC or GND,I <sub>OUT</sub> = 0		5.5	_	_	10	μΑ
Increase in I <sub>CC</sub>	per input	Δlcc	V <sub>IN</sub> = 3.4 V (one input)		5.5	_	_	2.5	mA

Note 1: Typical values are at  $V_{CC} = 5 \text{ V}$ ,  $Ta = 25^{\circ}C$ .

Note 2: It recommends that this device uses Pull-up resistance when adding and using resistance for an output terminal. Since it couses to drop a VOH voltage level when using Pull-down resistance for an output terminal.

Note 3: Measured by the voltage drop between A and B pins at the indicated current through the switch. On resistance is determined by the lower of the voltages on the two (A or B) pins.

# AC Characteristics ( $Ta = -40 \sim 85$ °C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Propagation delay time (bus to bus)	t <sub>pLH</sub>	Figure 1, Figure 2 (Note 4)	4.5	-	0.32	ns
Output enable time	t <sub>pZL</sub> t <sub>pZH</sub>	Figure 1, Figure 3	4.5	I	4.5	ns
Output disable time	t <sub>pLZ</sub>	Figure 1, Figure 3	4.5	_	5.0	ns

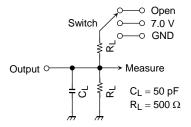
Note 4: The propagation delay time is calculated by the RC (on-resistance and load capacitance) time constant.

## **Capacitive Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Control pin input capacitance	C <sub>IN</sub>	(Note 5)	5.0	3	pF
Switch terminal capacitance	C <sub>I/O</sub>	OE = GND (Note 5)	5.0	10	pF

Note 5: This parameter is guaranteed by design.

## **AC Test Circuit**



Parameter	Switch
t <sub>pLH</sub> , t <sub>pHL</sub>	Open
t <sub>pLZ</sub> , t <sub>pZL</sub>	7.0 V
t <sub>pHZ</sub> , t <sub>pZH</sub>	GND

Figure 1

#### **AC Waveform**

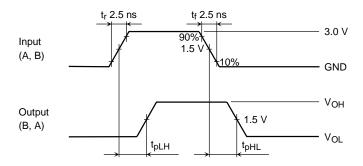


Figure 2 t<sub>pLH</sub>, t<sub>pHL</sub>

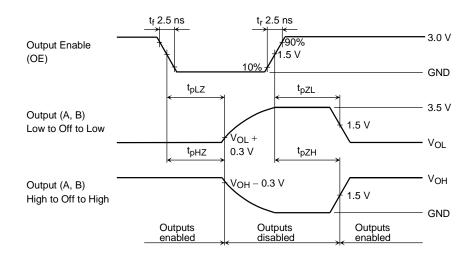
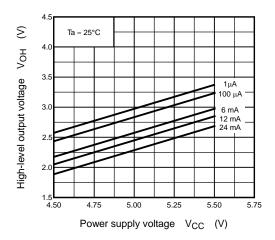
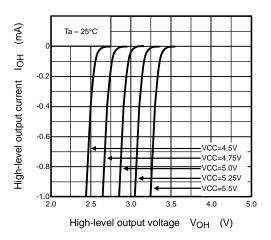
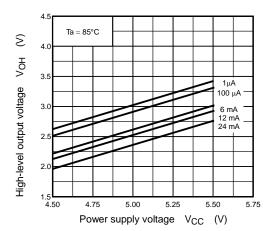


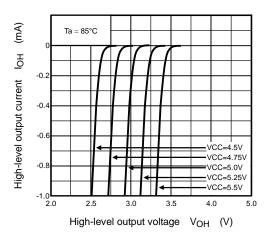
Figure 3  $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$ 

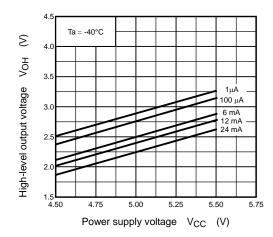
# V<sub>OH</sub> – V<sub>CC</sub> Characteristics (typ.)











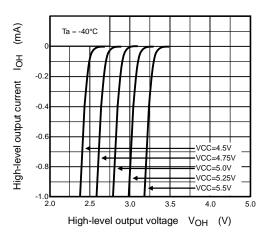
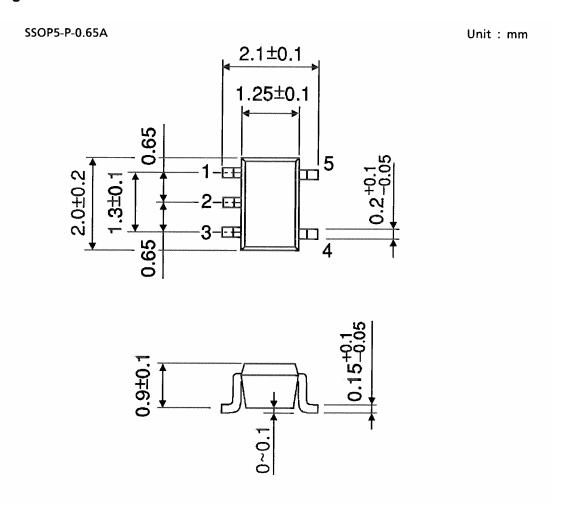


Figure 4

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# **Package Dimensions**



Weight: 0.006 g (typ.)

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